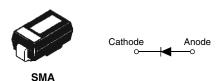


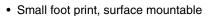
Vishay High Power Products

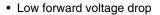
Schottky Rectifier, 2.1 A



PRODUCT SUMMARY			
I _{F(AV)}	2.1 A		
V_{R}	60 V		

FEATURES







- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- · Designed and qualified for industrial level

DESCRIPTION

The 20MQ060NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	2.1	Α	
V_{RRM}		60	V	
I _{FSM}	t _p = 5 μs sine	40	Α	
V _F	2 Apk, T _J = 125 °C	0.68	V	
TJ	Range	- 55 to 150	°C	

VOLTAGE RATINGS				
PARAMETER SYMBOL		20MQ060NPbF	UNITS	
Maximum DC reverse voltage	V_{R}	60	V	
Maximum working peak reverse voltage	V_{RWM}	60	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at $T_C = 107$ °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		2.1	А
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	40	А
See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	10	A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25$ °C, $I_{AS} = 1$ A, $L = 4$ mH		2.0	mJ
Repetitive avalanche current	I _{AR}			1.0	Α

Document Number: 94592 Revision: 24-Jul-08

20MQ060NPbF

Vishay High Power Products Schottky Rectifier, 2.1 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} ⁽¹⁾	2 A		0.78	V
		1.5 A	T _J = 25 °C	0.71	
Maximum forward voltage drop		1 A		0.63	
See fig. 1		2 A		0.68	
		1.5 A	T _J = 125 °C	0.63	
		1 A		0.57	
Maximum reverse leakage current	. (1)	T _J = 25 °C	V _R = Rated V _R	0.5	- mA
See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C		7.5	
Threshold voltage	V _{F(TO)}	$T_{J} = T_{J} \text{ maximum}$ 0.45 86.8		0.45	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	C _T	V _R = 10 V _{DC} , T _J = 25 °C, test signal = 1 MHz		31	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/μs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approvimate weight			0.07	g
Approximate weight		0.002	OZ.	
Marking device		Case style SMA (similar D-64)	V2	2H

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

Document Number: 94592 Revision: 24-Jul-08



Schottky Rectifier, 2.1 A Vishay High Power Products

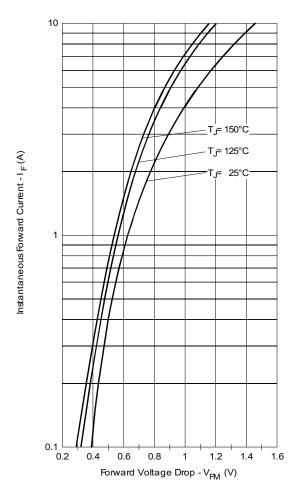


Fig. 1 - Maximum Forward Voltage Drop Characteristics

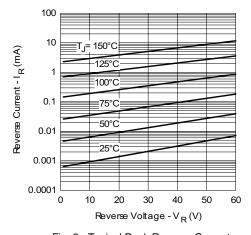


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

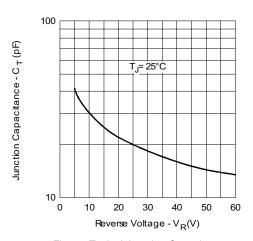


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

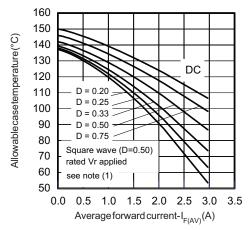


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

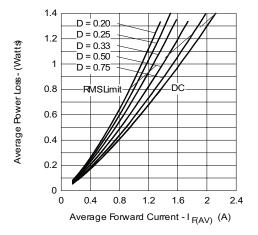


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R

Vishay High Power Products Schottky Rectifier, 2.1 A



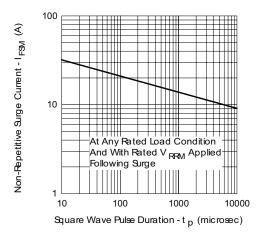
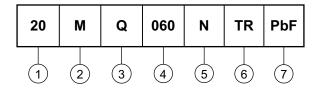


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

ORDERING INFORMATION TABLE

Device code



- 1 Current rating
- 2 M = SMA
- 3 Q = Schottky "Q" series
- Voltage rating (060 = 60 V)
- 5 N = New SMA
- 6 • None = Box (1000 pieces)
 - TR = Tape and reel (7500 pieces)
- | 7 | PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95018			
Part marking information	http://www.vishay.com/doc?95029		
Packaging information	http://www.vishay.com/doc?95034		

For technical questions, contact: diodes-tech@vishay.com

Document Number: 94592

Revision: 24-Jul-08



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com